

Small Signal Schottky Diode

Features

- For general purpose applications
- This diode features low turn-on voltage and high break-down voltage. This device is protected by a PN junction guardring against excessive voltage, such as electrostatic discharges.
- This diode is also available in the DO35 case with type designation BAT46 and in the SOD123 case with type designation BAT46W-V.
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

Mechanical Data

Case: MiniMELF Glass case (SOD80)

Weight: approx. 31 mg

Cathode Band Color: black

Packaging Codes/Options:

GS18/10 k per 13" reel (8 mm tape), 10 k/box GS08/2.5 k per 7" reel (8 mm tape), 12.5 k/box

Parts Table

Part	Ordering code	Type Marking	Remarks
LL46	LL46-GS18 or LL46-GS08	-	Tape and Reel

Absolute Maximum Ratings

 $T_{amb} = 25 \ ^{\circ}C$, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit	
Repetitive peak reverse voltage		V _{RRM}	100	V	
Forward continuous current	T _{amb} = 25 °C	١ _F	150 ¹⁾	mA	
Repetitive peak forward current	t_p < 1 s, δ < 0.5, T_{amb} = 25 °C	I _{FRM}	350 ¹⁾	mA	
Surge forward current	$t_p = 10 \text{ ms}, \text{ T}_{amb} = 25 ^\circ\text{C}$	I _{FSM}	750 ¹⁾	mA	
Power dissipation ¹⁾	T _{amb} = 80 °C	P _{tot}	200 ¹⁾	mW	

¹⁾ Valid provided that electrodes are kept at ambient temperature

Thermal Characteristics

$T_{amb} = 25 \,^{\circ}C$, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Thermal resistance junction to ambient air		R _{thJA}	300 ¹⁾	K/W
Junction temperature		Tj	125	°C
Ambient operating temperature range		T _{amb}	- 55 to + 125	°C
Storage temperature range		T _{stg}	- 65 to + 150	°C

¹⁾ Valid provided that electrodes are kept at ambient temperature



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Electrical Characteristics

 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Reverse breakdown voltage	$I_R = 100 \ \mu A \ (pulsed)$	V _(BR)	100			V
Leakage current ²⁾	V _R = 1.5 V	I _R			0.5	μA
	V _R = 1.5 V, T _j = 60 °C	I _R			5	μA
	V _R = 10 V	I _R			0.8	μA
	$V_{R} = 10 \text{ V}, \text{ T}_{j} = 60 ^{\circ}\text{C}$	I _R			7.5	μA
	V _R = 50 V	I _R			2	μA
	$V_R = 50 \text{ V}, \text{ T}_j = 60 ^\circ\text{C}$	۱ _R			15	μA
	V _R = 75 V	I _R			5	μA
	$V_R = 75$ V, $T_j = 60$ °C	I _R			20	μΑ
Forward voltage ²⁾	I _F = 0.1 mA	V _F			250	mV
	I _F = 10 mA	V _F			450	mV
	I _F = 250 mA	V _F			1000	mV
Diode capacitance	V _R = 0 V, f = 1 MHz	CD		10		pF
	V _R = 1 V, f = 1 MHz	CD		6		pF

 $^{2)}$ Pulse test t_p < 300 µs, δ < 2 %

Typical Characteristics

 T_{amb} = 25 °C, unless otherwise specified

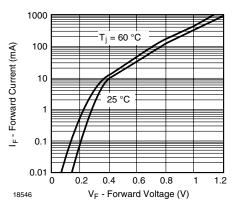
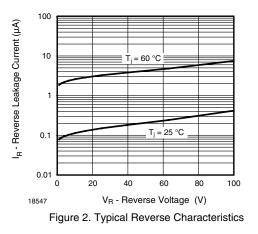


Figure 1. Typical Instantaneous Forward Characteristics







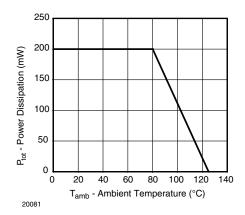
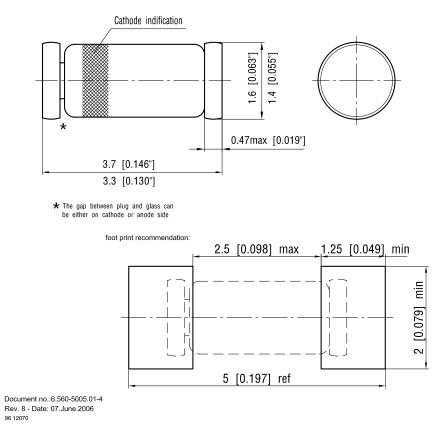


Figure 3. Admissible Power Dissipation vs. Ambient Temperature





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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

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